Gray scale processor (32 tones) BU2134AK

The BU2134AK is an LSI designed for use in image scanners and facsimile machines, with a function which takes analog image signals output from an image sensor in an image processing device and converts them to binary format.

This product is equipped with an internal 6-bit A/D converter, image sensor control circuit, and CPU interface, and can be configured easily for data reading.

Applications Facsimile machines, word processors, and other similar devices

Features

- 1) Internal 6-bit A/D converter. (internal data width after shading : 5 bits)
- Shading correction function.
- 3) ABC (Auto Background Control) function.
- 4) Pseudo intermediate processing based on organizational dither method.
- 5) Pseudo intermediate processing based on error dispersion method.
- 6) Simple binary processing.
- 7) 2-dimensional edge enhancement and 2-dimensional character enhancement.
- 8) γ correction.
- 9) Reduction in horizontal direction.

Block diagram



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Image processing ASSP for FAX

FAX

Parameter	Symbol	Limíts	Unit
Power supply voltage	Vod	-0.3~7.0	v
Input voltage	Vin	-0.3~Vpp+0.3	V
Analog power supply voltage	AVoo	0.3~Vpp+0.3	V
Analog input voltage	AVIN	-0.3~AVpp+0.3	v
Operating temperature	Торт	0~70	ĉ
Storage temperature	Tstg	-55~150	°C
Input current	lin	±20	mA
Output current	lo	±20	mA
Power dissipation	Pd	800*	mW

* Reduced by 8mW for each Increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Unless otherwise noted, Ta=25℃, Vob=5V)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Power supply voltage	VDD	4.75	5	5.25	V
Input voltage	Vin	0	_	VDD	V
Analog power supply voltage	AVDD	0	_	Vod	V
Analog ground voltage	Agnd	_	0	· _	v
Reference voltage +	Ref+	3		AVDD	v
Reference voltage —	Ref-	0	_	1	v
Analog input voltage	Ain	Ref-	<u> </u>	REF+	v

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Parameter	Pin Name	I/O	Function
Video signal output	DTO	Output	Outputs binary video signal as serial data.
······	MA13~MA00	Output	Outputs external SRAM address; MA13 is MSB.
	MD7~MD0	Input/Output	Data bus for external SRAM; MD7 is MSB.
ine memory interface.	ŌE	Output	Output Enable signal for external SRAM (negative logic)
	WE	Output	Write Enable signal for external SRAM (negative logic)
	AB3~AB0	Input	Address Input pin; AB3 is MSB.
	D87~D80	Input/Output	Data Input/output pin; DB7 is MSB.
	WA	Input	Write input pin for setting internal register (negative logic)
	RD	Input	Read input pin for reading internal register (negative logic)
CPU interface	DREQ	Output	Outputs DMA Request signal in parallel mode. Outputs DTO latch clock in serial mode.
	DACK	Input/Output	Inputs DMA Acknowledge signal in parallel mode (negative logic). Outputs DTO Enable signal in serial mode (negative logic).
	CS	Input	Chip Select input pin which enables access to internal register (negative logic)
	RST	Input	System reset input pin (negative logic)
System clock	SCLK	Input	System clock input pin
Line start	LNST	Input	Inputs line start signal.
	φ 1	Output	Output pin 1 for image sensor drive clock
	¢2	Output	Output pin 2 for Image sensor drive clock
Image sensor interface	RS	Output	Image sensor reset signal output pin.
interface	∳ TG	Output	Image sensor transfer gate pulse output pin.
	CLP	Output	Analog ground signal
	AINO	Input	Inputs image sensor analog video signals.
	AIN1	Input	Inputs analog signals (such as temperature sensor).
Analog interface	REF+	—	Connect this to reference voltage of the A/D converter full-scale point.
	REF	_	Connect this to reference voltage of the A/D converter zero point.
	Vod		Connect this to the digital power supply (+5 V) (Pin 3).
Power supply and	GND	_	Connect this to the digital ground (Pin 4).
Power supply/ground	aVo	—	Connect this to the analog power supply (Pin 1).
	AGND	_	Connect this to the analog ground (Pin 1).

Commun	ication	ICs
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°in No.	1/0	Pin Name	Pin No.	1/0	Pin Name	Pin No.	1/0	Pin Name	Pin No.	1/0	Pin Name
1	0	MA00	17	0	OE	33	1/0	D85	49	ν	AVDD
2	0	MA01	18	[:] 0	WE	34	1/0	DB6	50	I	AIN 0
З	0	MA02	19	1/0	MD0	35	1/0	DB7	51	Ι	AIN 1
4	0	MA03	20	1/0	MD1	36	1	ABO	52		REF+
5	0	MA04	21	1/0	MD2	37	I	AB1	53		REF-
6	0	MA05	22	1/0	MD3	38	I	AB2	54	G	AGND
7	0	MA06	23	1/0	MD4	39	I	AB3	55		NC
8	G	GND	24	G	GND	40	G	GND	56	V	Voo
9	ν	VDD	25	1/0	MD5	41	V	VDD	57	0	¢ 1
10	0	MA07	26	1/0	MD6	42	1/0	DAĊK	58	0	¢2
11	0	MA08	27	1/0	MD7	43	0	DREQ	59	0	RS
12	0	MA09	28	1/0	DB0	44	I	WR	60	0	∳ TG
13	0	MA10	29	1/0	DB1	45	I	RD	61	0	CLP
14	0	MA11	30	1/0	DB2	46	I	CS	62	ο	DTO
15	0	MA12	31	1/0	DB3	47	I	RST	63	G	GND
16	0	MA13	32	1/0	DB4	48		LNST	64		SCLK

CMOS level input: SCLK, LNST, RST, CS

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Fig. 1

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Bi-directional CMOS, bi-directional TTL

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Electrical characteristics

DC characteristics (Unless otherwise noted, Ta=25°C, VDD=5V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage "H"	ViH	3.5	<u> </u>	Voo	v	CMOS level
Input voltage "L"	Vil	0	_	1.5	V	CMOS level
Input voltage "H"	νн	2.4	_	Vod	V	TTL level
Input voltage "L"	VIL	0	_	0.8	V	TTL level
Input current "H"	liki Iiki		_	-10	μA	VH=VDD
Input current "L"	hr.			10	μΑ	VL=GND
Output current "H"	юн	-1.0	_	_	mA	
Output current "L"	loi.	3.2	_	-	mA	V _{OL} =0.4V
Output leakage current	loz		_	±10	Α	Vo=Vop or GND
Static current consumption	İst	_	_	100	μA	VI=VDD or GND

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●Switching characteristics (Unless otherwise noted, Ta=25℃, Voo=5V)

	Parameter	No.	Min.	Тур.	Max.	Unit
	System clock cycle, tcyc	1	100	-	_	ns
System clock	System clock pulse width "H", twh	2	40	—		ns
	System clock pulse width "L" ,twl	3	40	—	_	ns
	CS ~ WR, RD setup time	4	0	-	_	ns
	AB ~ WR, RD setup time	5	20	-	—	ns
	DB ~ WR setup time	6	50	-	_	ns
CPU interface	WR, RD pulse width	7	100	_	_	ns
	WR, RD ~ CS hold time	8	0	-	_	ns
	WR, RD ~ AB hold time	9	20		_	ns
	WR ~ DB hold time	10	20	—	_	ns
	RD ~ DB hold time	10	0	_	_	ns
	Read cycle time	11		tcyc		ns
	MA, MCS ~ OE setup time	12	_	twh	—	ns
	OE pulse width	13		twl	—	ns
	OE ~ MA, MCS hold time	14	0			ns
SRAM interface	Write cycle time	15	-	tcyc	_	ns
	MA, MCS ~ WE setup time	16		twh	_	ns
	MD ~ WE setup time	17	-	twi	. —	ns
	WE pulse width	18	_	twl		กร
	WE ~ MA, MCS hold time	19	0	_	_	ns
	WE ~ MD hold time	20	0		_	ns

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SRAM INTERFACE



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Description of register functions

Address	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	R	w
0	*8	*7	*6	*5	*4	*3	*2	*1	0	0
1	* 14		*13		*12	*11	* 10	*9	×	0
2	0	* 20	*	19	* 18	* 17	*16	* 15	×	0
3	Line clamp/start position MSB is #			#	O		*21		×	0
4	# Line cla			_ine clamp/	end position	n			×	0
5	Distortion correction start position					×	0			
6	0		ABC start position						×	0
7	ABC end position							×	0	
8	*22						0	0		
9				*	23				×	0
Α		*	25			*	24		×	0
В	*	27	0		* 26				×	0
С	* 29				*28				×	0
D		*	31		* 30				×	0
E	0		* 33			*	32		×	0

* 1	White reference screen scan (read enal	(beld
	When 0 :	Stop
	When 1	Start
*2	Offset scan (read enabled)	
	When 0:	Stop
	When 1:	Start
×З	Binary processing (read enabled)	
	When 0 :	Stop
	When 1 :	Start
*4	ABC Enable (read enabled)	
	When 0 :	Off
	When 1:	On
× 5	ABC initialization	
	When 0 :	Off
	When 1	On
*6	Data table/Write Enable	
	When O:	Writing of data table to Address 8 is off
	When 1:	Writing of data table to Address 8 is on
	1) For simple binary processing :	5 bits \times 32 words (gamma correction data)
	2) For dither method :	5 bits $ imes$ 64 words (slice data)
	3) For error dispersion method :	5 bits \times 32 words (density adjustment data)
*7	White reference data/Write Enable	· · · · · · · · · · · · · · · · · · ·
	When O:	Writing of white reference data to Address 8 is off
	When 1:	Writing of white reference data to Address 8 is on
×8	White reference data/Read Enable	•
	When O :	Reading of white reference data from Address 8 is of
	When 1	Reading of white reference data from Address 8 is or
*9	Binary video signal output mode	
	When O :	Binary video signals are output as serial data.
	When 1:	Binary video signals are output as parallel data.
* 10	Parallel mode specification	,
	When O :	First bit of binary video signal is taken as LSB.
	When 1:	First bit of binary video signal is taken as MSB.
k 1 1	Binary video signal selection	
	When 0:	Black = 0, White = 1
	When 1	Black = 0, White = 0

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×12 Offs	set correc	tion				
Wh	ien 0 :		Off			
Wh	ien 1 :		On			
		ple/hold tir	•			
	ien 000 :		Sampled at \$	-		
	en 001 :		Sampled at S			
	en 010 :		Sampled at 5			
	ien 011 :		Sampled at S	-		
	ien 100 :		Sampled at S	-		
	ien 101 :		Sampled at S	-		
	en 110 :		Sampled at S	-		×
	ien 111 : Dissovert	or chonnol	Sampled at 8			14
	ien 0 ;	er channel	Connected to			Į
	ien 1 :		Connected to			L S
	age sensc		Connected (AS
	ien 0 :	,, ,,	CCD			ing.
	en 1:		CIS			ess
	rG output	logic	<i>414</i>			ğ
,	ien 0 :		Positive logic			D D
	en 1:		Negative log			Image processing ASSP for FAX
		output logi				토
	en O :		Positive logic			
	en 1 :		Negative log			
* 18 Cla	mping m	ethod				
Wh	en D :		Bit clamping			-
Wh	nen 1 :		Line clampin	ġ		FAX
*19 ¢1	l clock an	d RS outpu	it specification			E
1)	¢ 1 clock	duty (when	using CIS)			
Wh	ien 00 :		HIGH for S0	to S3 cycles, LOW for S4 to S7 cycles		
Wh	ien 01 :		HIGH for S0	to S3 cycles, LOW for S4 to S7 cycles		
Wh	өл 10 :		HIGH for S0	to S1 cycles, LOW for S2 to S7 cycles		
Wh	neri 11 :		HIGH for S0	to S5 cycles, LOW for S6 to S7 cycles		
2) F	RS output	position (w	vhen using CCD)			
Wh	en 00 :		Output at \$5	cycle		
Wh	en 01 :		Output at S6	cycle		
	rG pulse v					
	ien using	CCD				
	en 0 :		Output at S1			
	nen 1 :		Output at S0	to S7 cycles		
	ien using	ÇIŞ				
	ien O :			to S0 cycles		
	ien 1 :		•	to S7 cycles		
*21 Ori	iginal widt	h specifica	tion			
DB2	DB1	DB0	Distortion correction width	Reading width	Reading position	
0	0	0	1728	1728 (A4, 8dot / mm or equivalent)		
0	0	1	2048	1728 (A4, 8dot / mm or equivalent)	Center	
	1	0	2048	2048 (B4, 8dot / mm or equivalent)		
0					· · · · · · · · · · · · · · · · · · ·	
n	1	1	2432	1728 (A4, 8dot / mm or equivalent)	Center	
0		0	2432	2048 (B4, 8dot / mm or equivalent)	Center	
1	0					
	0	1	2432	2432 (A3, 8dot / mm or equivalent) 2592 (A4, 12dot / mm or equivalent)		

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*22 Numerator of reduction ratio in horizontal direction

*23 Denominator of reduction ratio in horizontal direction *23

The reduction ratio is set as shown below, using Address 8 (numerator) and Address 9 (denominator).

	Reduction ratio = (value s	
		for reduction ration denominator) + 1
*24	Black follow-up speed	
	When 0 :	ABC circuit not followed on dark background
	When 1 to 15:	The larger the set value, the faster the ABC is followed on a dark background.
*25	White follow-up speed	
	When 0 :	ABC circuit not followed on light background
	When 1 to 15:	The larger the set value, the faster the ABC is followed on a light background.
*26	Binary parameter	
	1) For simple binary processing :	Set the slice level.
	2) For organizational dither processing	This parameter is invatid.
	3) For error dispersion processing :	Set the black level.
*27	Binary mode	-
	When 00 :	Simple binary processing
	When 01	Simple binary processing
	When 10:	Pseudo intermediate processing using organizational dither method
	When 11:	Pseudo intermediate processing using error dispersion method
* 28	Degree of edge enhancement in horizonta	
	When 0:	Edge erihancement off
	When 1 to 15	The larger the set value, the stronger the enhancement will be.
* 29	Degree of edge enhancement in vertical d	
	When 0:	Edge enhancement off
	When 1 to 15	The larger the set value, the stronger the enhancement will be.
*30	Correction parameter in horizontal direction	
		etermine whether or not edge enhancement is to be carried out when the amount of density in the
	horizontal direction is changed.	
₩3 1	Correction parameter in vertical direction	atomics whather as eat advantations are to be apprend out when the amount of density in the vertical
		etermine whether or not edge enhancement is to be carried out when the amount of density in the vertical
+ 00	direction is changed.	
* 32	Character enhancement parameter B	used this parameter is used as a threshold to determine whether as not adap aphaneoment is to be
		used, this parameter is used as a threshold to determine whether or not edge enhancement is to be
+ 22	•	both the horizontal and vertical directions is changed.
+ 33	Character enhancement parameter A	ncement when pseudo intermediate processing is used.
	2) When using the dither method	cement when pseudo intermediate processing is used.
	When 000 :	Character enhancement of
	When 001 to 111 :	Character enhancement off The larger the set value, the stronger the enhancement will be.
	3) When using the error dispersion metho	
	When 000 :	Character enhancement off
	When 001 to 111 :	The larger the set value, the stronger the enhancement will be.
404	Resetting the internal registers of Address	
# 34	The set values for other internal registers (
* 35	Register setting unit	to not change when a resol is initiated.
* 00	1) The line clamping start and end position	as can be specified in units of 1 oivel
	2) The distortion correction start position	
	 The ABC start and end positions can be 	
* 36	In the following cases, Address 8 should b	
	1) Writing data tables	a and an reasing and writing of logic.
	 Peading and writing white reference da 	ta



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Fig. 8 Scan timing diagram







Fig. 10 Output timing diagram (parallel mode)





External dimensions (Units: mm)



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